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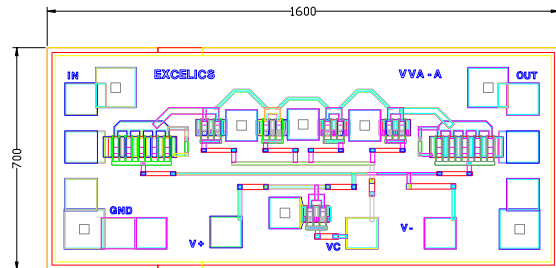
DC – 26GHz VOLTAGE VARIABLE ATTENUATOR MMIC

FEATURES

- Broadband Performance: DC-26GHz
- Wide Attenuation Range: 25dB
- Low Insertion Loss: 2.5dB
- Good Return Loss: 10dB

APPLICATIONS

- Point-to-point and point-to-multipoint radio



ELECTRICAL CHARACTERISTICS (T_a = 25 °C)

PARAMETERS/TEST CONDITIONS		MIN	TYP	MAX	UNIT
Operating Frequency Range		DC		26	GHz
Input Power at 1dB Compression		6	8		dBm
Input Power at 0.25dB Compression		-5	-2		dBm
Minimum Attenuation	(DC - 8GHz)		1.5	2.5	dB
	(8 - 26GHz)		2.5	3.5	dB
Maximum Attenuation	(DC – 8GHz)		25	30	dB
	(8 - 26GHz)		30	35	dB
Return Loss	@min. attenuation	10	15		dB
	@max. attenuation	10	12		dB

ABSOLUTE MAXIMUM RATINGS FOR CONTINUOUS OPERATION^{1,2}

RF Input Power	+16dBm
Control Voltage	+1.0 to -8 Volts
Storage Temperature	-65 to 150 deg C
Operating Temperature	-55 to +125 deg C

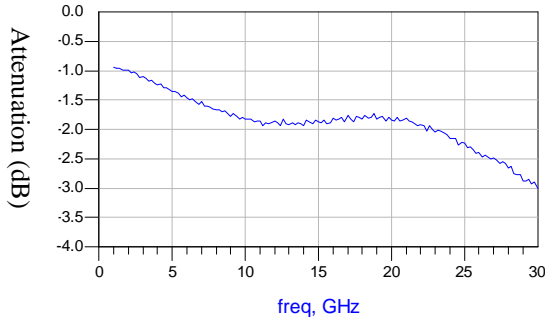
1. Operating the device beyond any of the above rating may result in permanent damage.



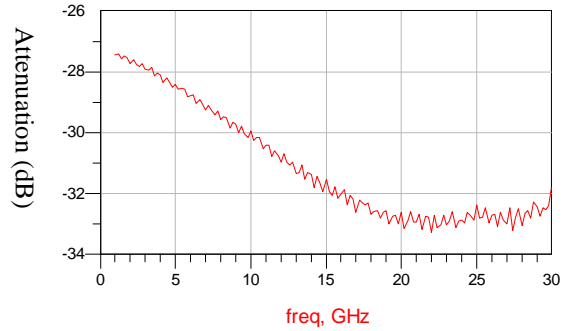
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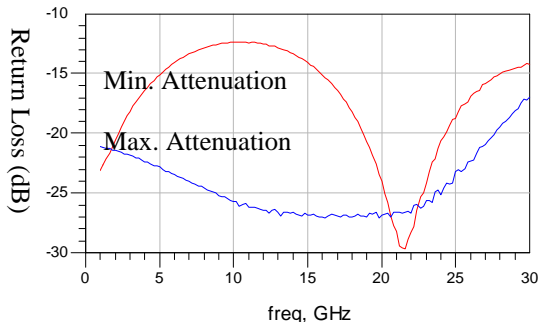
INSERTION LOSS



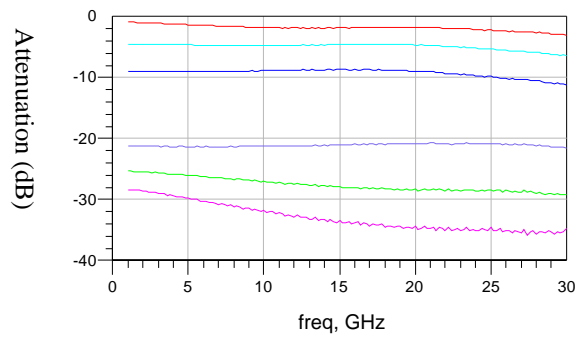
ATTENUATION RANGE



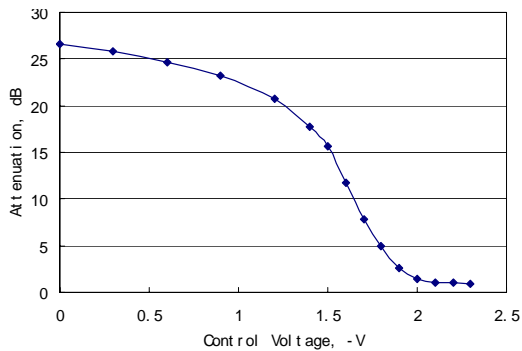
RETURN LOSS



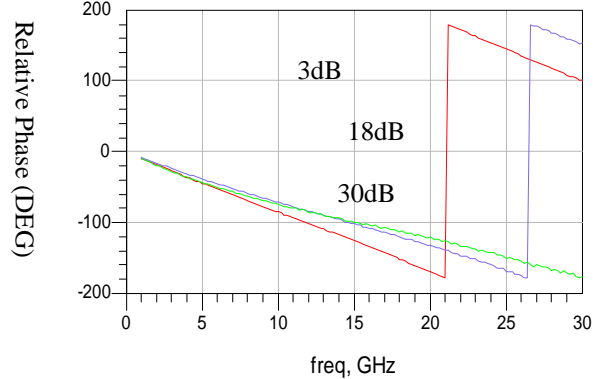
RELATIVE ATTENUATION



RELATIVE ATTENUATION VS. CONTROL VOLTAGE @2GHz



RELATIVE PHASE

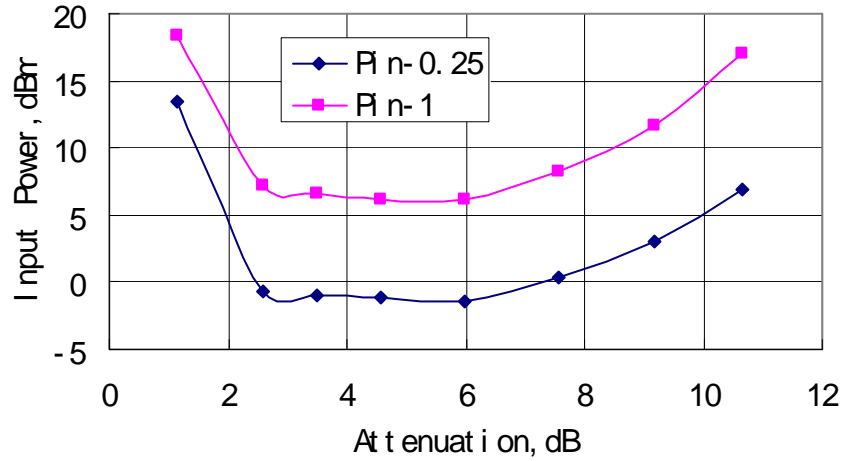




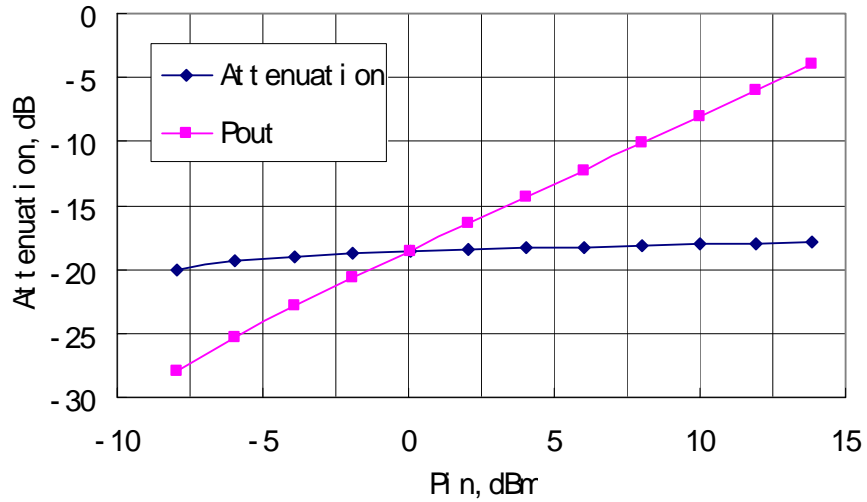
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DC – 26GHz VOLTAGE VARIABLE ATTENUATOR MMIC

Input Power at 1dB and 0.25dB Compression VS. Attenuation



Pout and Attenuation VS. Pin at High Attenuation Setting

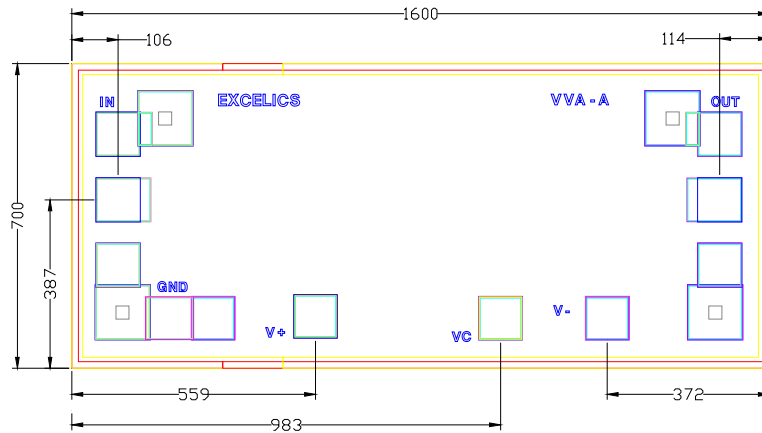




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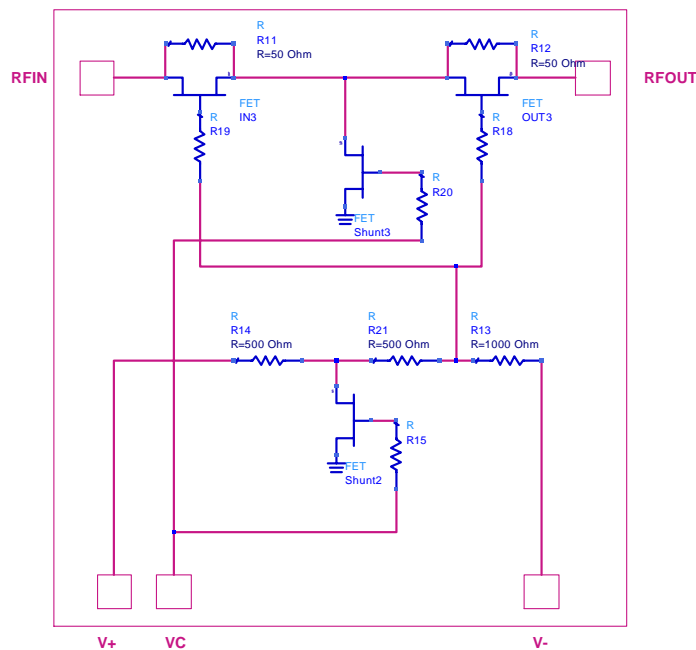
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Outline Drawing



All dimensions in microns
 Bond pads are 100microns by 100microns
 Die thickness is 75±13 microns
 Backside metallization: GOLD
 Bond pads metallization: GOLD

On Chip DC Conversion Circuit



On chip DC conversion circuit maintains impedance match while attenuation is varied. Apply +6V to V+ and -6V to V-. Input control voltage which will be applied to VC ranges from 0V (max. attenuation) to -4V (min. attenuation).